

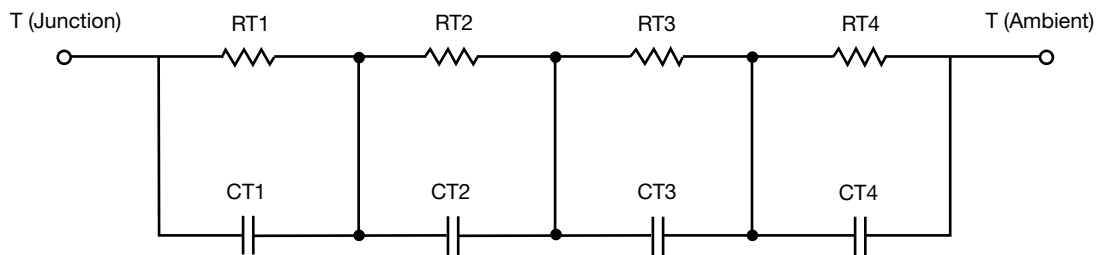
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION

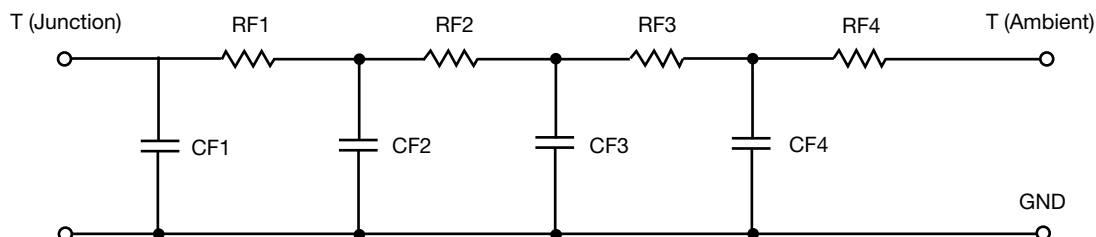


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	4.1459	740.5859m	N/A
RT2	19.9929	910.8433m	N/A
RT3	12.9917	1.0463	N/A
RT4	32.5254	1.5245	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	800.9505u	241.0045u	N/A
CT2	801.4770m	9.0340m	N/A
CT3	44.6295m	29.8575m	N/A
CT4	3.5701	2.9782m	N/A

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION

R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	4.4762	1.2356	N/A
RF2	12.8051	1.4012	N/A
RF3	22.9291	45.9081m	N/A
RF4	29.3529	1.4940	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	1.1555m	306.2783u	N/A
CF2	36.6809m	2.4813m	N/A
CF3	472.5804m	51.2240u	N/A
CF4	2.8344	3.7492m	N/A

Note

N/A indicates not applicable

